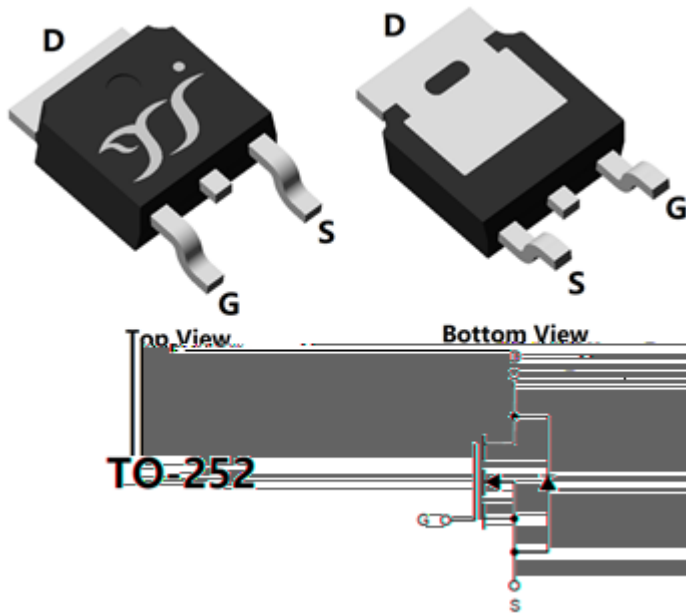




YJD50G15H

N-Channel Enhancement Mode Field Effect Transistor



Product Summary

V_{DS}	150V
I_D	50A
$R_{DS(ON)}$ (at $V_{GS}=10V$)	19m
$R_{DS(ON)}$ (at $V_{GS}=6V$)	22m
100% EAS Tested	
100% V_{DS} Tested	

General Description

Split gate trench MOSFET technology
 Low $R_{DS(on)}$ & FOM
 Excellent stability and uniformity
 Moisture Sensitivity Level 1
 Epoxy Meets UL 94 V-0 Flammability Rating
 Halogen Free

Applications

Power management
 Portable equipment

Absolute Maximum Ratings ($T_A=25$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	150	V
Gate-source Voltage		V_{GS}	± 20	V
Drain Current	$T_A=25^\circ C$	I_D	7.4	A
	$T_A=100^\circ C$		5.2	
	$T_C=25^\circ C$		50	
	$T_C=100^\circ C$		35	
Pulsed Drain Current ^A		I_{DM}	160	A
Avalanche energy ^B		EAS	256	mJ
Total Power Dissipation ^C	$T_A=25^\circ C$	P_D	3	W
	$T_A=100^\circ C$		1.5	
	$T_C=25^\circ C$		150	
	$T_C=100^\circ C$		75	
Junction and Storage Temperature Range		T_J, T_{STG}	-55 +175	$^\circ C$

Thermal resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient ^D	Steady-State	R	40	50	$^\circ C/W$
Thermal Resistance Junction-to-Case	Steady-State	R	0.8	1	

Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJD50G15H	F1/F2	YJD50G15H	2500	/	25000	

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Typical Electrical and Thermal Characteristics Diagrams

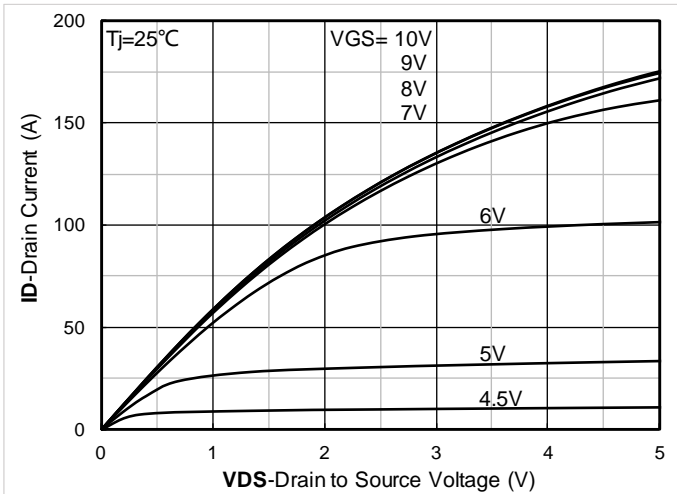


Figure 1. Output Characteristics

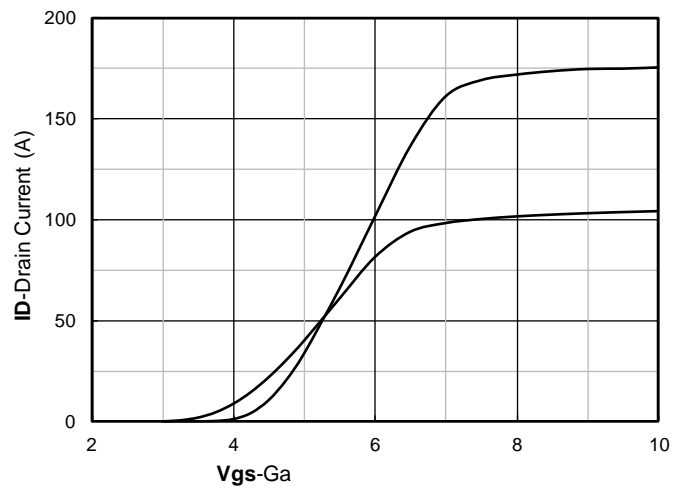


Figure 2. Transfer Characteristics

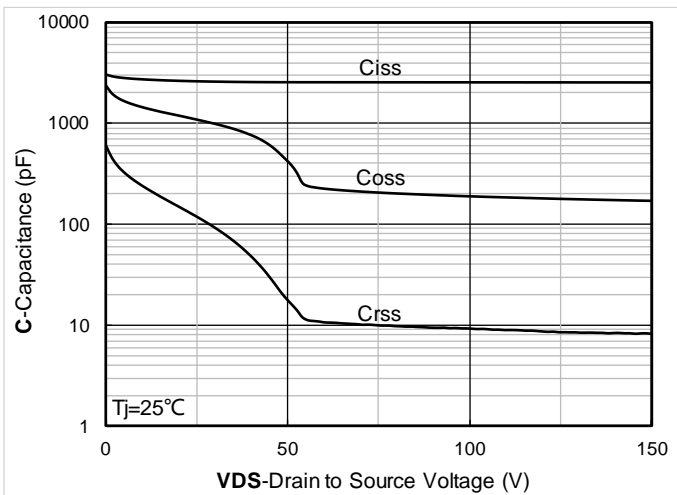


Figure 3. Capacitance Characteristics

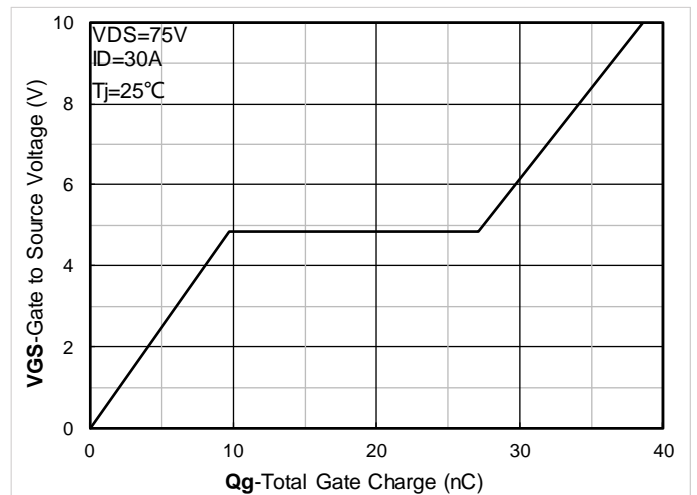


Figure 4. Gate Charge



Figure 5. On-Resistance vs Gate to Source Voltage

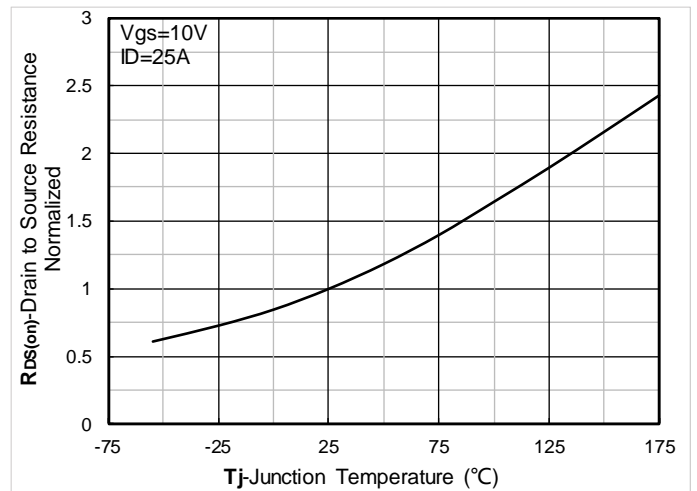


Figure 6. Normalized On-Resistance



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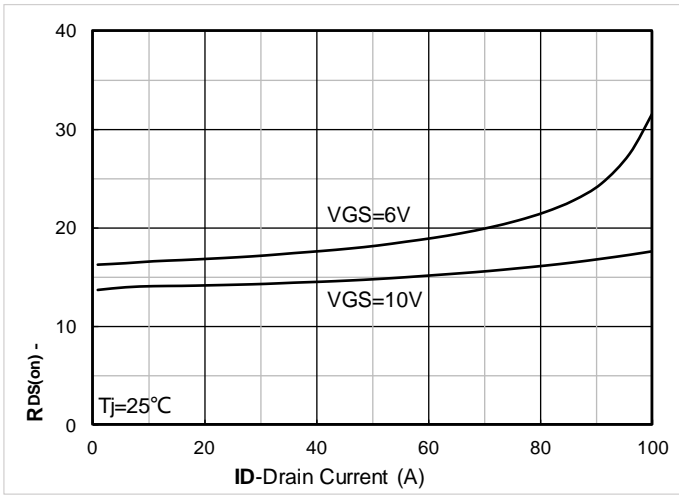


Figure 7. RDS(on) VS Drain Current

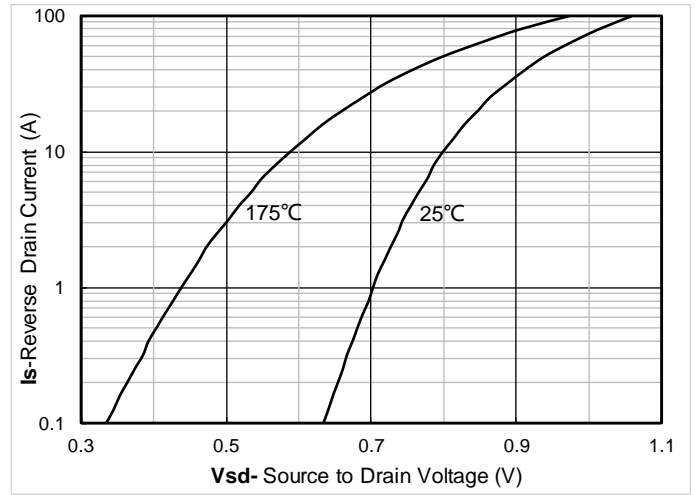


Figure 8. Forward characteristics of reverse diode

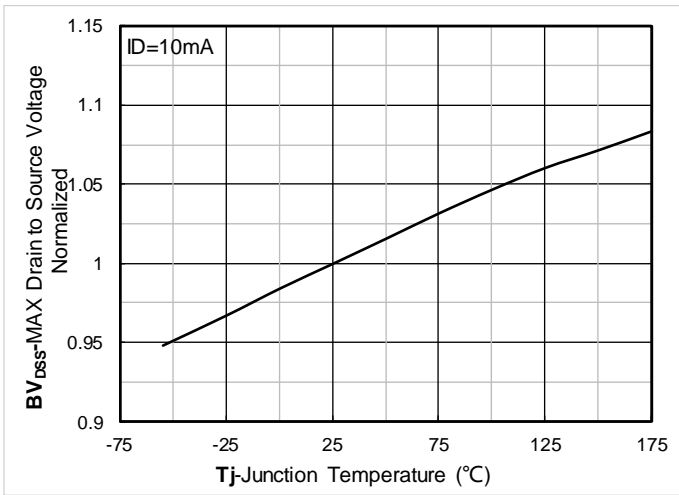


Figure 9. Normalized breakdown voltage

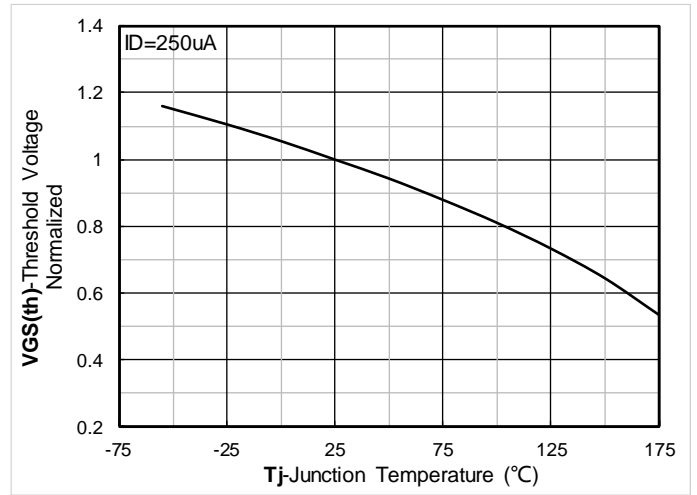


Figure 10. Normalized Threshold voltage

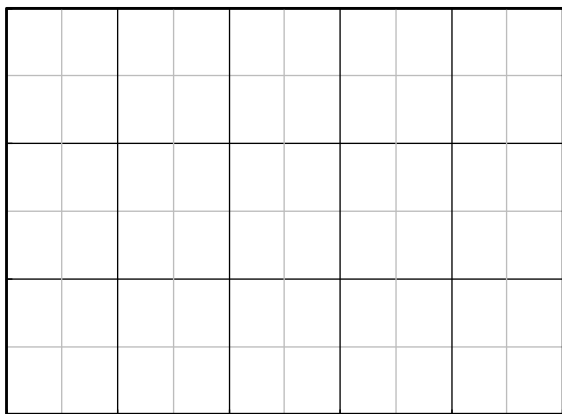


Figure 11. Current dissipation

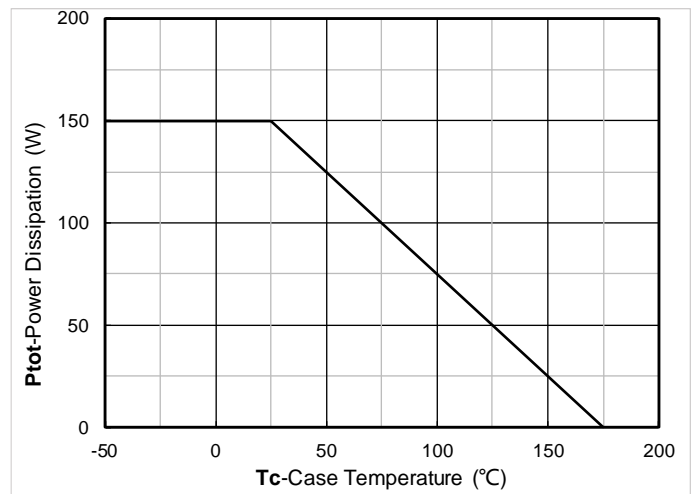


Figure 12. Power dissipation

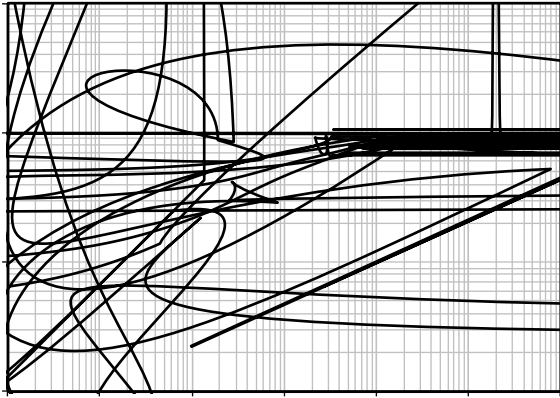


Figure 13. Maximum Transient Thermal Impedance

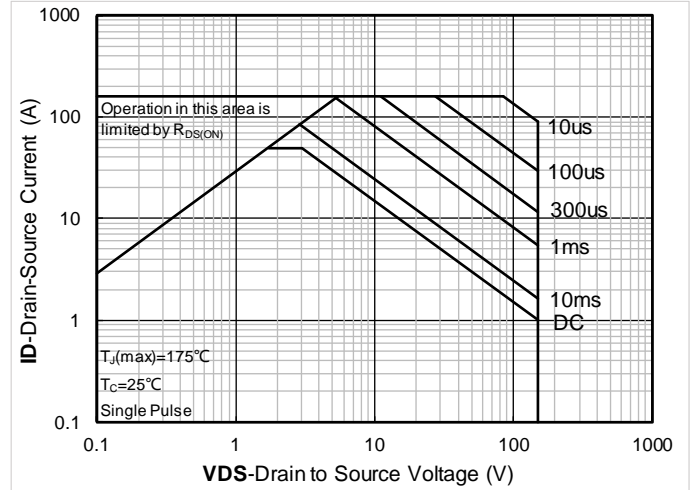


Figure 14. Safe Operation Area

Test Circuits & Waveforms

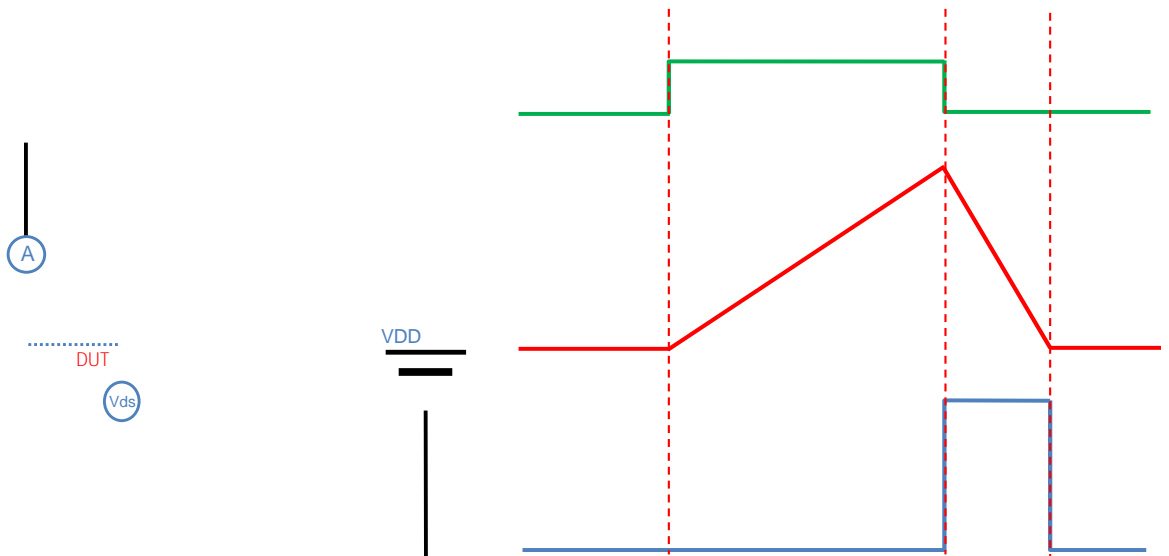


Figure A. Unclamped Inductive Switching (UIS) Test Circuit & Waveform

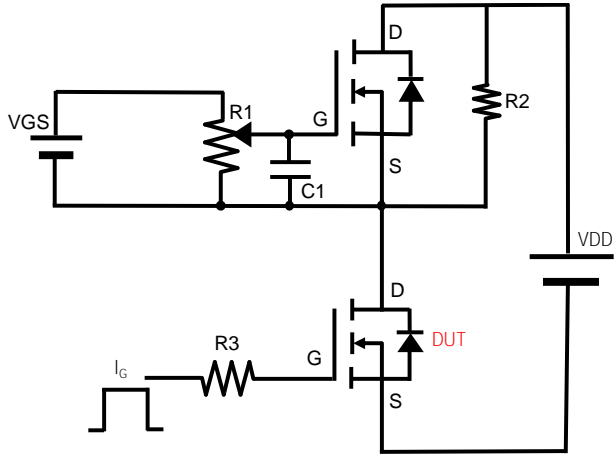


Figure B. Gate Charge Test Circuit & Waveform

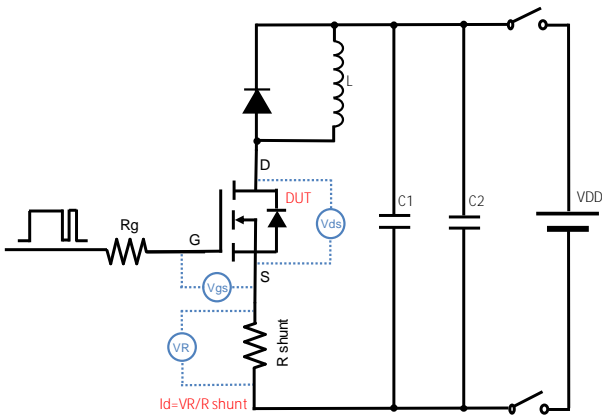


Figure C. Resistive Switching Test Circuit & Waveform

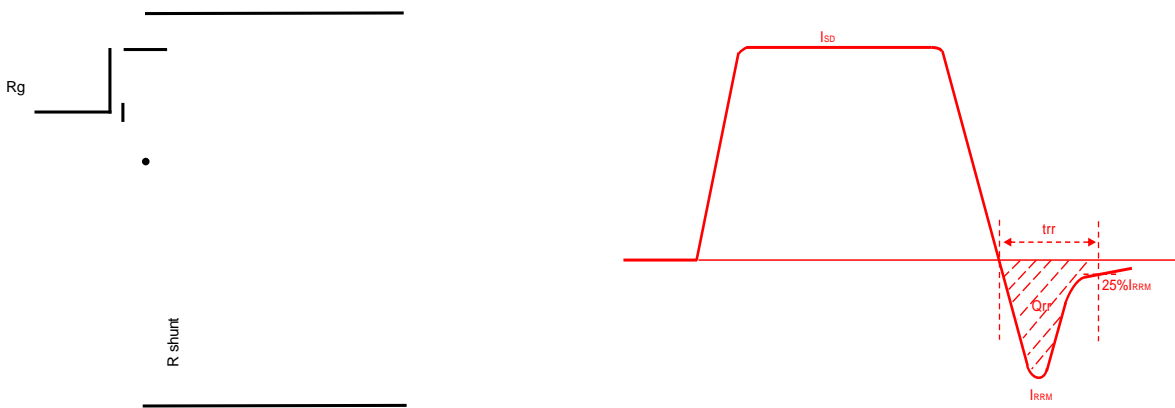
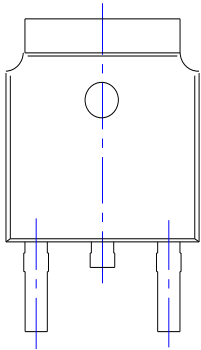


Figure D. Diode Recovery Test Circuit & Waveform



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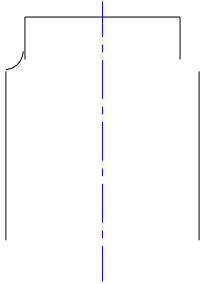
TO-252-B Package information



TOP VIEW



SIDE VIEW



BOTTOM VIEW

SUGGESTED SOLDER PAD LAYOUT

DIMENSIONS					
SYMBOL	INCHES				
	MIN.	NOM.			
A1	0.000				
A2	0.087	0.091			
A3	0.035	0.039			
b	0.026	0.030			
c	0.018	0.020			
D	0.256	0.260			
D1					
D2	0.181	0.189			
E	0.390	0.398			
E1	0.236	0.240			

NOTE:

- 1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
- 2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
- 3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.



YJD50G15H

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